NSN 5961-01-196-6939

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-196-6939 **Inclosure Material:** Plastic **Overall Length:** 0.360 inches **Overall Height:** 0.183 inches **Overall Width:** 0.410 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-202 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 12.0 emitter to base voltage, static, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6599a professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No